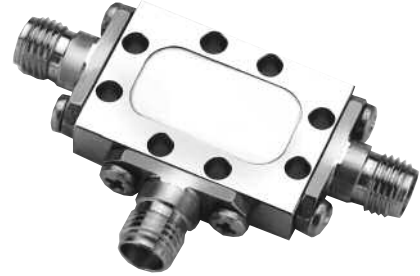


MODEL: BMA0218LA1MD (Modulation Driven)

FEATURES

- RF frequency range..... 2 to 18 GHz
- Modulation bandwidth DC to 0.5 GHz
- Biphase accuracy..... $\pm 5^\circ$
- Amplitude accuracy ± 0.5 dB
- Modulator to RF isolation..... 20 dB

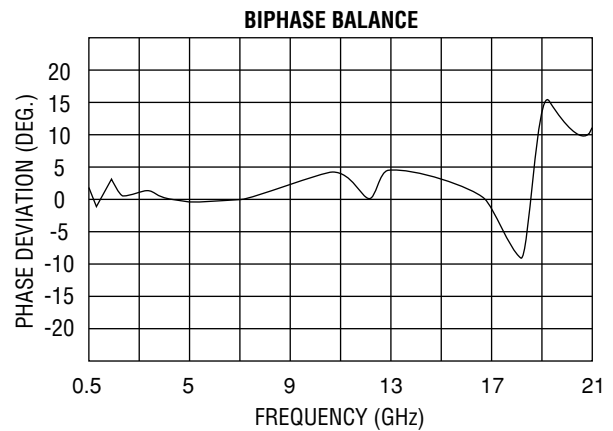
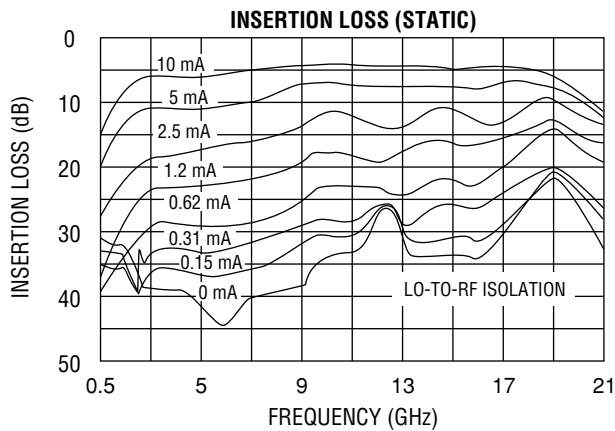
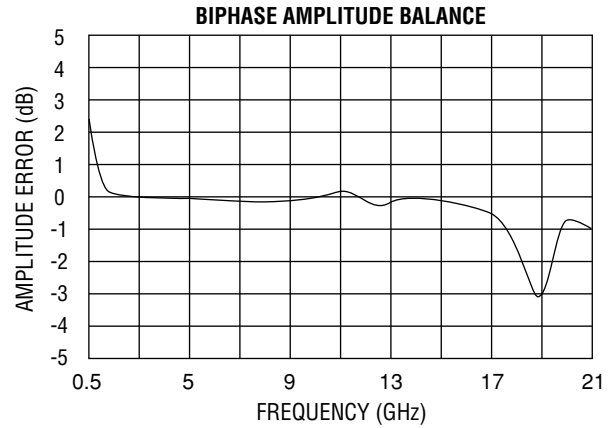
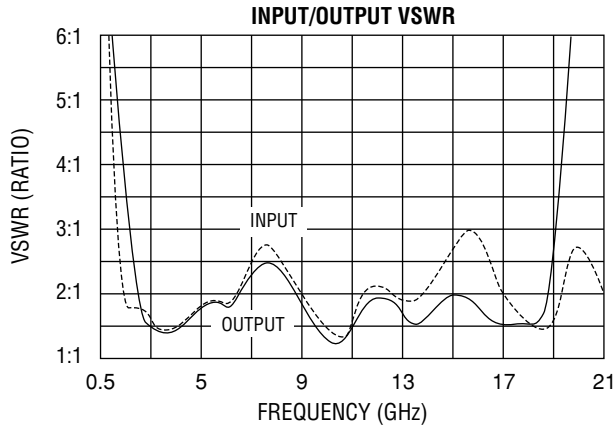


This double-balanced multioctave mixer is suitable for general purpose biphase modulator applications. When the diodes are driven by the carrier power (mode 1), a 10 to 15 dB IF amplitude control is possible. In the modulation driven mode, close, biphase control of the carrier is possible over a wide RF dynamic range. The specifications shown below are for the modulation driven mode (linear RF). An optional model (-CD) can be ordered and tested in the carrier driven or linear modulation mode.

ELECTRICAL SPECIFICATIONS

INPUT PARAMETERS	CONDITION	UNITS	MIN.	TYP.	MAX.
RF frequency range		GHz	2		18
RF power		dBm	Noise		+5
RF VSWR		Ratio		2:1	
IF frequency range		GHz	DC		0.5
IF current (antiparallel diode input)		mA	-10		+10
TRANSFER CHARACTERISTICS	CONDITION	UNITS	MIN.	TYP.	MAX.
Biphase accuracy	2 to 18 GHz 3 to 17 GHz	Degrees		5 2	10 5
Biphase amplitude balance	IF = ± 10 mA	dB		0.5	
Switch loss	IF = ± 10 mA	dB		3	5
Isolation	RF in to RF out	RF = +10, IF = Off	18	20	
	IF in to RF in	RF = +10, IF = Off		15	
	IF in to RF out	RF = +10, IF = Off		30	
OUTPUT PARAMETERS	CONDITION	UNITS	MIN.	TYP.	MAX.
RF frequency range (modulated carrier)		GHz	2		18
RF power at 1 dB compression		dBm		0	
RF VSWR		Ratio		2.5:1	

BMA0218LA1MD MODULATION DRIVEN TYPICAL TEST DATA



MAXIMUM RATINGS

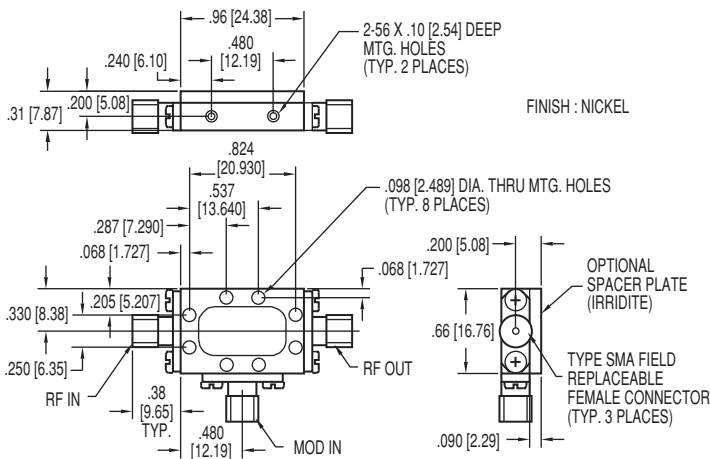
Specification temperature..... +25°C
 Operating temperature -54 to +85°C
 Storage temperature -65 to +95°C

GENERAL NOTE

1. Linear RF or modulation driven mode (RF = 0 dBm, IF = ±10 mA).

NOTE: Test data supplied at 25°C; insertion loss and biphas accuracy.

OUTLINE DRAWING



NOTE: All dimensions shown in brackets [] are in millimeters.

BLOCK DIAGRAM

